

Heavy fermion behavior in PrRh₂B₂C: Excitonic mass enhancement

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We report magnetic and transport properties of a quaternary borocarbide PrRh₂B₂C based on magnetization, resistivity, and specific-heat studies. This compound forms in LuNi₂B₂C-type tetragonal structure (space group *I4/mmm*) and does not exhibit magnetic ordering or superconductivity down to 0.5 K. The crystal-field analysis of specific-heat data suggests a singlet ground state in this compound. The high value of the Sommerfeld coefficient, $\gamma \approx 250$ mJ/mole K², together with a singlet ground state suggests that the heavy fermion behavior in PrRh₂B₂C results from the interaction of the conduction electrons with the low-lying crystal-field excitations. No signature of magnetic ordering or superconductivity is observed in PrRh₂B₂C under the application of pressure up to 23 kbar.

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I. INTRODUCTION

The heavy fermion systems have fascinated the condensed matter physicists with the exciting physics in the vicinity of quantum critical point. Most of the known heavy fermion systems belong to Ce-, Yb- or U-based intermetallic compounds. Recently discovered Pr-based heavy fermion superconductor PrOs₄Sb₁₂ (Ref. 1) presents many unusual phenomena such as two distinct superconducting phases, time reversal symmetry breaking, point nodes at Fermi surface, etc.¹⁻⁵ In contrast to the numerous Ce-based magnetically mediated heavy fermion superconductors, PrOs₄Sb₁₂ is the only known Pr-based heavy fermion superconductor. Further, in contrast to the case of Ce compounds where spin Kondo effect leads to the heavy fermion behavior, in Pr compounds such as PrInAg₂ and PrFe₄P₁₂ it is the quadrupolar Kondo effect which is suggested to be responsible for heavy fermion behavior.^{6,7}

Another important mechanism for mass enhancement in Pr compounds is the inelastic scattering of conduction electrons by the angular momentum associated with the crystal electric field (CEF) levels referred to as excitonic mass enhancement. The theory of excitonic mass enhancement was proposed by White and Fulde⁸ to explain the mass enhancement in elemental Pr itself and subsequently extended to rare-earth systems with a CEF-split nonmagnetic singlet ground state.⁹ The true realization of heavy fermion behavior due to crystal-field excitons was found in PrOs₄Sb₁₂ with a Sommerfeld coefficient $\gamma \approx 350$ mJ/mole K².⁵ Very recently we have seen evidence of excitonic mass enhancement in Pr₂Rh₃Ge₅ leading to moderate heavy fermion behavior.¹⁰ We present further evidence for excitonic mass enhancement in PrRh₂B₂C in this Brief Report. In addition to providing one more example of Pr-based heavy fermion compound through our analysis of specific-heat data we attempt to provide a qualitative explanation of the unusual route to the heavy fermion state in this compound. PrRh₂B₂C is a member of the quaternary borocarbide family that gives rise to the hope to provide a route to high-temperature superconductivity in boron based compounds which provided a unique play-

ground to investigate the interplay between superconductivity and magnetism. We present in this Brief Report electrical resistivity, magnetic susceptibility, and specific-heat data of a Pr-based quaternary compound. The reproducibility of the results has been checked by similar studies on a second batch of samples.

II. EXPERIMENTAL

We prepared polycrystalline samples of PrRh₂B₂C and the nonmagnetic reference compound LaRh₂B₂C starting with high purity elements (99.99% or better) in stoichiometric composition by the standard arc melting on water cooled copper hearth. During the arc melting process samples were flipped and melted several times to improve the homogeneity. Arc melted samples were annealed for a week at 1200 °C under dynamic vacuum. Samples were characterized by copper K_{α} x-ray diffraction (XRD) and scanning electron microscopy. A SQUID magnetometer was used for magnetization measurements. Heat capacity was measured by relaxation method in a physical property measurement system (PPMS, Quantum Design), and electrical resistivity was measured by the standard ac four probe techniques using the ac-transport option of PPMS. Electrical resistivity measurements under hydrostatic pressure were carried out in a double-layer piston-cylinder type pressure cell for pressures up to 23 kbar. Silicone fluid served as pressure transmitting medium. The pressure was determined at low temperatures by monitoring the pressure induced shift of the superconducting transition temperature of lead. The narrow width of the transition confirmed the good hydrostatic pressure conditions inside the pressure cell.

III. RESULTS AND DISCUSSION

The powder XRD data of a polycrystalline sample of PrRh₂B₂C were analyzed by WINXPOW software and further refined by least-squares Rietveld refinement method using the FULLPROF software (Fig. 1), the quality parameter χ^2 be-

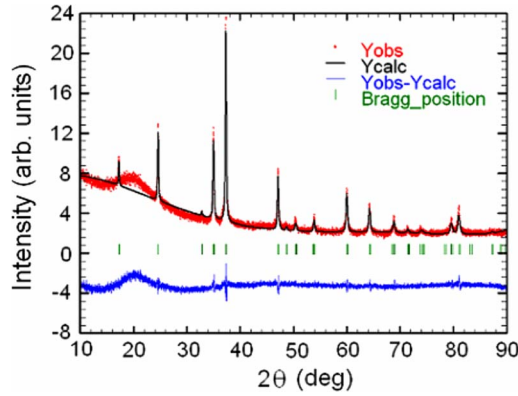


FIG. 1. (Color online) Powder x-ray diffraction pattern of $\text{PrRh}_2\text{B}_2\text{C}$ recorded at room temperature. The solid line through the experimental points is the Rietveld refinement profile calculated for $\text{LuNi}_2\text{B}_2\text{C}$ -type tetragonal $I4/mmm$ structural model. The lower-most curve represents the difference between the experimental and model results.

ing 2.82. $\text{PrRh}_2\text{B}_2\text{C}$ forms in $\text{LuNi}_2\text{B}_2\text{C}$ -type tetragonal structure (space group $I4/mmm$) with lattice constants $a = 3.855 \text{ \AA}$, $c = 10.257 \text{ \AA}$ and unit cell volume $= 152.44 \text{ \AA}^3$. The nonmagnetic reference compound $\text{LaRh}_2\text{B}_2\text{C}$ also crystallizes in the same tetragonal structure with lattice constants $a = 3.896 \text{ \AA}$, $c = 10.247 \text{ \AA}$ and unit cell volume $= 155.53 \text{ \AA}^3$, which are in fairly good agreement with the values reported.¹¹ From XRD and scanning electron microscope (SEM) image we estimate impurity phase(s) to be less than 3% of the main phase.

The magnetic susceptibility data of $\text{PrRh}_2\text{B}_2\text{C}$ are shown in Fig. 2 as a function of temperature. No anomaly is seen in the susceptibility down to 2 K. At higher temperatures the susceptibility curve follows a Curie-Weiss behavior $\chi = C/(T - \theta_p)$. From the linear fit of inverse susceptibility data at 1.0 T we obtained the effective moment $\mu_{\text{eff}} = 3.59 \mu_B$, which is very close to the theoretically expected value of $3.58 \mu_B$ for Pr^{3+} ion. The paramagnetic Curie-Weiss temperature, $\theta_p = -3.9 \text{ K}$. The inset of Fig. 2 shows the magnetic-field dependence of isothermal magnetization, $M(B)$ of

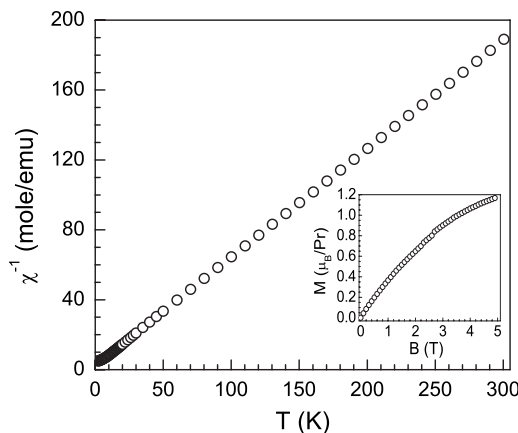


FIG. 2. Temperature dependence of inverse magnetic susceptibility of $\text{PrRh}_2\text{B}_2\text{C}$ measured in a field of 1.0 T. The inset shows the field dependence of isothermal magnetization at 2 K.

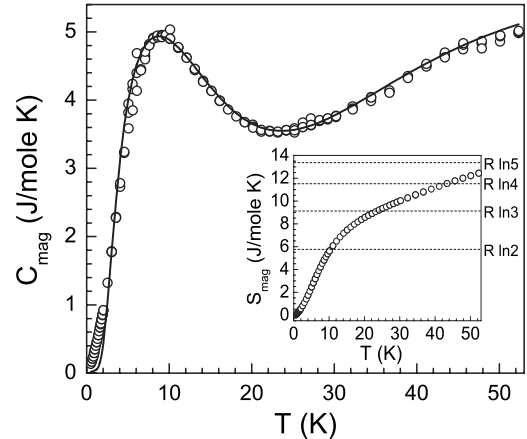


FIG. 3. Magnetic part of specific heat of $\text{PrRh}_2\text{B}_2\text{C}$ as a function of temperature. Solid line shows the fit to the CEF scheme as described in the text. Inset shows the temperature dependence of magnetic part of entropy.

$\text{PrRh}_2\text{B}_2\text{C}$. The isothermal magnetization at 2 K shows slight nonlinearity, most likely due to the crystal-field effects [the kink in $M(B)$ near 2.7 T is an experimental artifact]. The magnetization does not reach the saturation value up to 5 T; it attains a value of $1.17 \mu_B$ at 5 T.

The specific-heat data of $\text{PrRh}_2\text{B}_2\text{C}$ do not show any anomaly corresponding to a magnetic or superconducting transition down to 0.5 K. However, a broad Schottky-type anomaly centered around 9 K is observed in the magnetic part of specific heat. The magnetic contribution to the specific heat, obtained by subtracting the specific heat of $\text{LaRh}_2\text{B}_2\text{C}$ from that of $\text{PrRh}_2\text{B}_2\text{C}$, assuming the lattice contribution to be approximately equal to the specific heat of $\text{LaRh}_2\text{B}_2\text{C}$ is shown in Fig. 3. The experimentally observed feature of the magnetic part of the specific heat above 2 K could be reproduced by a CEF analysis with four levels: three singlets at 0, 14, and 36 K and a doublet at 155 K. The solid line in Fig. 3 represents the fit with this CEF level scheme. The inset of Fig. 3 shows the magnetic contribution to the entropy of $\text{PrRh}_2\text{B}_2\text{C}$. The magnetic entropy attains a value of $R \ln(2)$ at 10 K supporting the proposed CEF level scheme of a singlet ground state lying below the first excited singlet at 14 K. From the specific-heat data below 2 K we estimate a lower bound to the value of Sommerfeld coefficient $\gamma \approx 250 \text{ mJ/mole K}^2$. It is observed that below 0.5 K C/T increases with decreasing temperature (inset of Fig. 4) while C keeps on decreasing. Such a behavior of specific heat suggests a gradual onset of heavy fermion state and has some similarity with the C/T upturn in heavy fermion compounds $\text{YbNi}_2\text{B}_2\text{C}$ (Ref. 12) and YbRh_2Si_2 .¹³ However, we cannot entirely exclude the possibility that sharp increase in C/T might be related to the onset of phase transition at further lower temperatures.

The electrical resistivity of $\text{PrRh}_2\text{B}_2\text{C}$ shown in Fig. 4 exhibits metallic behavior with $\rho_{300 \text{ K}} = 68 \mu\Omega \text{ cm}$, residual resistivity $\rho_0 \approx 42 \mu\Omega \text{ cm}$, and residual resistivity ratio $\text{RRR} = \rho_{300 \text{ K}}/\rho_0 \approx 1.6$. At higher temperatures the resistivity decreases almost linearly with decreasing temperature. We attribute the anomaly around 10 K to be due to crystal-field

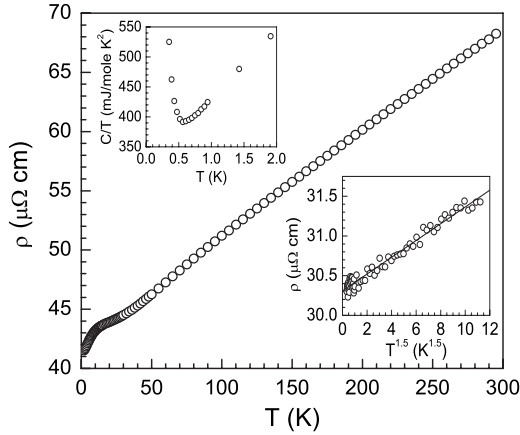


FIG. 4. Temperature dependence of electrical resistivity of $\text{PrRh}_2\text{B}_2\text{C}$ in the temperature range 0.5–300 K. The lower inset shows the electrical resistivity data below 5 K plotted as ρ vs $T^{1.5}$ (measured on second sample). The solid line is a guide for the eyes. The upper inset shows the low-temperature specific-heat data below 2 K plotted as C/T vs T .

effect which is consistent with the specific-heat data. The electrical resistivity of $\text{LaRh}_2\text{B}_2\text{C}$ which we measured down to 0.5 K also shows metallic behavior. A rapid drop is observed in resistivity of the La-based compound below 3 K possibly due to incipient superconductivity.

The low-temperature electrical resistivity data of $\text{PrRh}_2\text{B}_2\text{C}$ fit well with $\rho(T) = \rho_0 + AT^n$ with $n \approx 1.5$ and $A = 0.1 \mu\Omega \text{ cm}/\text{K}^n$ and is shown in the inset of Fig. 4 plotted as ρ vs $T^{1.5}$ below 5 K. A $T^{1.5}$ temperature dependence of the electrical resistivity is a characteristic of non-Fermi-liquid behavior as predicted by the spin fluctuation theory for a three-dimensional system near an antiferromagnetic quantum critical point (AF-QCP). However in our compound because of the singlet ground state the departure from the Fermi liquid behavior is more likely to be due to the presence of low-lying CEF levels. Further on, the residual resistivity is rather high which makes the power-law exponent not so reliable. Therefore, we refrain from putting too much stress on the resistivity exponent and the associated non-Fermi-liquid nature and proximity of $\text{PrRh}_2\text{B}_2\text{C}$ to an AF-QCP.

We also calculated the value of Wilson ratio using the value of $\chi = 0.25 \text{ emu/mole}$ at 2 K and $\mu_{\text{eff}} = 3.59 \mu_B$ together with $\gamma \approx 250 \text{ mJ/mole K}^2$ and obtained $R_w = 17$ which is

quite large. The high value of electronic specific-heat coefficient γ together with the enhanced value of R_w is a clear indication of strong correlations and heavy fermion behavior in this compound. Since no Kondo-type behavior is observed in $\rho(T)$, the mechanism for the heavy fermion behavior may be rooted in the low-lying CEF splitting similar to that in the heavy fermion superconductor $\text{PrOs}_4\text{Sb}_{12}$.^{1,5} It was suggested by Fulde and Jensen⁹ that for a system with CEF-split singlet ground state and low CEF splitting energy the inelastic scattering of conduction electrons with the excited levels of angular momentum of the $4f$ electrons can result in an enhanced mass of the conduction electrons. After a rigorous theoretical analysis they have shown that the enhanced mass due to the inelastic transition between two levels i and j can be found by the expression⁹

$$\frac{m^*}{m} = 1 + (g_J - 1)^2 J_{sf}^2 N(0) \frac{2|\langle i|J|j \rangle|^2}{\Delta},$$

where J_{sf} is the exchange integral coupling between the conduction electrons and the f electrons, and $N(0)$ conduction electron density of states at the Fermi level. The matrix element between i and j can be calculated using the CEF parameters. An inelastic neutron-scattering experiment on $\text{PrRh}_2\text{B}_2\text{C}$ is highly desired to know the exact CEF level scheme and evaluate the matrix elements. The CEF analysis of specific-heat data clearly suggests a CEF-split singlet ground state with another singlet excited state at about 14 K and therefore an excitonic mass enhancement by the crystal-field excitations leading to the heavy fermion behavior in $\text{PrRh}_2\text{B}_2\text{C}$.

Using similar CEF analysis of magnetic specific-heat data we have seen that $\text{PrPd}_2\text{B}_2\text{C}$ also has a singlet ground state lying below the first excited singlet at 50 K and a doublet at 80 K.¹⁴ However, the value of Sommerfeld coefficient $\gamma \approx 16 \text{ mJ/mole K}^2$ is much lower than that of $\text{PrRh}_2\text{B}_2\text{C}$, consistent with the theory of White and Fulde,⁸ the γ value being inversely proportional to the separation between the ground state and the excited state. For a better insight of excitonic mass enhancement in Pr compounds with nonmagnetic singlet ground state we present the values of Sommerfeld coefficient γ , crystal-field splitting energy Δ , and low-temperature saturation value of magnetic susceptibility χ in Table I. A comparison of γ and Δ in these systems clearly reflects a systematic variation in their value; a smaller Δ

TABLE I. The Sommerfeld coefficient γ , crystal-field splitting energy Δ , and low-temperature saturation value of magnetic susceptibility χ for few Pr compounds having nonmagnetic singlet as ground state.

Compounds	Ground state	First excited state	Splitting energy Δ (K)	γ (mJ/mole K ²)	χ_0 ($\times 10^{-2}$ emu/mole) at 2 K
$\text{PrRh}_2\text{B}_2\text{C}$	Singlet	Singlet	14	250	20.4
$\text{Pr}_2\text{Rh}_3\text{Ge}_5$	Singlet	Singlet	12	81	10.6 ^a
$\text{PrPd}_2\text{B}_2\text{C}$	Singlet	Singlet	50	16	3.8 ^b
PrRhGe_3	Singlet	Doublet	70	10	3.8 ^c

^aReference 10.

^bReference 14.

^cReference 15.

results in an increased γ and vice versa. All these results establish the more general nature of the mechanism of excitonic mass enhancement in Pr compounds, and the mass enhancement due to low-lying crystal-field excitations can even lead to the development of heavy fermion state as in our system $\text{PrRh}_2\text{B}_2\text{C}$.

The application of pressure is expected to change the CEF level splitting energy and therefore to influence the physical properties. We therefore made an effort to achieve a stable ordered phase in $\text{PrRh}_2\text{B}_2\text{C}$ by applying external pressure. In the resistivity studies shown in Fig. 5 no significant effect (except a slight increase in magnitude of resistivity) of pressure was observed up to 23 kbar. Especially, the position of the anomaly around 10 K attributed to the CEF effect is independent of pressure (the inflection point in $d\rho/dT$ characterizing the position of anomaly changes almost negligibly for the pressures of 0, 1.33, and 2.24 GPa) indicating that the applied pressure of up to 23 kbar has no considerable effect on the CEF level splitting scheme. Furthermore, this pressure is not sufficient to stabilize any superconducting or magnetically ordered phase in $\text{PrRh}_2\text{B}_2\text{C}$. The insensitivity to external pressure can be explained in the very rigid framework of the $\text{RNi}_2\text{B}_2\text{C}$ structure as evidenced from a very high value of bulk modulus [e.g., $\text{YNi}_2\text{B}_2\text{C}$ (Ref. 16)].

IV. CONCLUSION

We present clear evidence of heavy fermion behavior in the quaternary borocarbide $\text{PrRh}_2\text{B}_2\text{C}$. The mechanism for the electronic mass enhancement in this case is not the usual Kondo effect but it is due to the low-lying crystal-field exci-

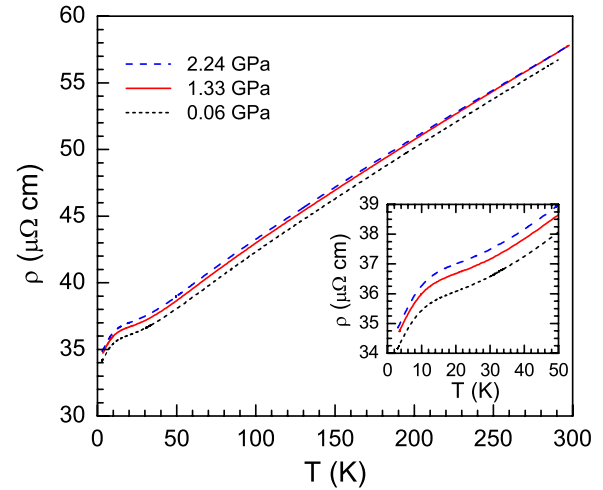


FIG. 5. (Color online) Electrical resistivity, $\rho(T)$, of $\text{PrRh}_2\text{B}_2\text{C}$ measured under the application of external pressures up to 23 kbar. Inset shows the extended view of low-temperature resistivity.

tations. In this compound the ground state is a singlet separated from the first excited state only by about 10 K. Our effort to induce magnetism or superconductivity using hydrostatic pressure did not succeed. This is attributed to extremely rigid frame of the borocarbide structure as evidenced from high bulk modulus of $\text{YNi}_2\text{B}_2\text{C}$.

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